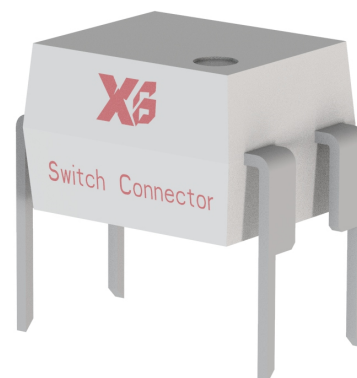


4 PIN DIP VERY HIGH ISOLATION VOLTAGE PHOTOCOUPLER CNY64 series, CNY65 series

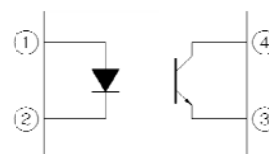


CNY64



CNY65

Schematic



Pin Configuration

1. Anode
2. Cathode
3. Emitter
4. Collector

Features:

- High Voltage , $BV_{CEO}=80V$ (min.)
- Operating temperature up to $+85^{\circ}C$
- High isolation voltage between input and output, $V_{iso} = 8200 V_{rms}$
- Rated recurring peak voltage (repetitive), $V_{ORM} = 1000 V_{RMS}$
- Creepage current resistance according to VDE 0303/IEC 60112 comparative tracking index: $CTI \geq 200$
- Thickness through insulation $\geq 3mm$
- Pb free and RoHS compliant.
- CUL approved (No. E214129)
- VDE approved (No. 40027351)
- FIMKO approved (No. 25464)

Description

The CNY64 and CNY65 series contains an infrared emitting diode optically coupled to a phototransistor. These devices are packaged in an 4-pin DIP package and providing a distance between input and output for highest safety requirement of $>3mm$.

Applications

- Switch mode power supply
- Line receiver
- Computer peripheral interface
- Microprocessor system interface
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
 - for appl. class I - IV at mains voltage $\leq 300 V$
 - for appl. class I - IV at mains voltage $\leq 600 V$
 - for appl. class I - III at mains voltage $\leq 1000 V$
 according to DIN EN 60747-5-5.

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	75	mA
	Peak forward current (<10μs)	I_{FM}	1.5	A
	Reverse voltage	V_R	5	V
	Power dissipation	P_D	120	mW
Output	Collector power dissipation	P_C	150	mW
	Collector current	I_C	50	mA
	Collector-Emitter voltage	V_{CEO}	80	V
	Emitter-Collector voltage	V_{ECO}	7	V
Total Power Dissipation		P_{TOT}	250	mW
Isolation Voltage* ¹		V_{ISO}	8200	V rms
Operating Temperature		T_{OPR}	-55 to 85	°C
Storage Temperature		T_{STG}	-55 to 100	°C
Soldering Temperature* ²		T_{SOL}	260	°C

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

*2 2mm from case, <10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward voltage	V_F	-	1.6	2.0	V	$I_F = 50\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R = 5\text{V}$
Input capacitance	C_{in}	-	-	100	pF	$V = 0, f = 1\text{MHz}$

Output

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	200	nA	$V_{CE} = 20\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 1\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}$
Collector-Emitter capacitance	C_{CE}	-	-	50	pF	$V_{CE} = 0\text{V}, f = 1\text{MHz}$

Transfer Characteristics

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Current Transfer ratio	CNY64	50	-	300	%	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$
	CNY65		-			
	CNY64A	63	-	125		
	CNY65A		-			
	CNY64B	100	-	200		
	CNY65B		-			
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	-	0.3	V	$I_F = 10\text{mA}, I_C = 1\text{mA}$
Isolation resistance	R_{IO}	10^{11}	-	-	Ω	$V_{IO} = 500\text{Vdc}$, 40~60% R.H.
Coupling capacitance	C_{IO}	-	0.3	-	pF	$V_{IO} = 0, f = 1\text{MHz}$
Turn-on time	T_{on}	-	6	18	μs	$V_{CC} = 5\text{V}$, $I_C = 5\text{mA}, R_L = 100\Omega$
Turn-off time	T_{off}	-	7	18		
Rise time	t_r	-	3	18		
Fall time	t_f	-	5	18		

* Typical values at $T_a = 25^\circ\text{C}$

Typical Electro-Optical Characteristics Curves

Figure 1. Forward Current vs. Forward Voltage

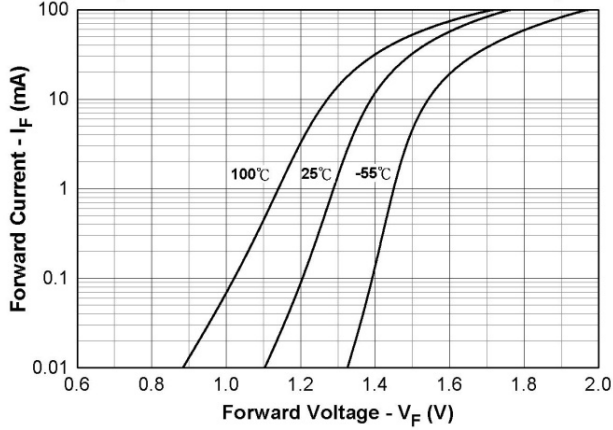


Figure 2. Normalized Current Transfer Ratio vs. Forward Current

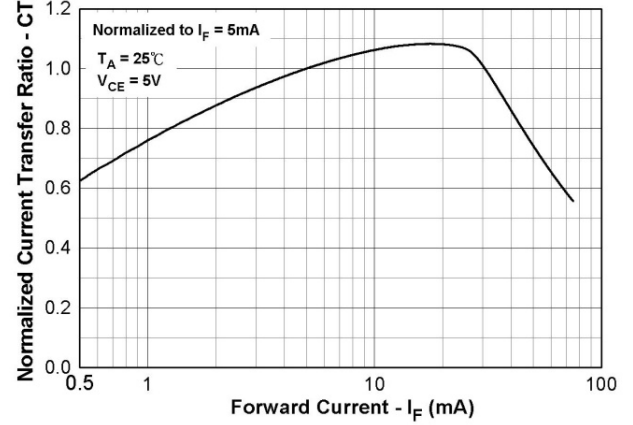


Figure 3. Normalized Current Transfer Ratio vs. Ambient Temperature

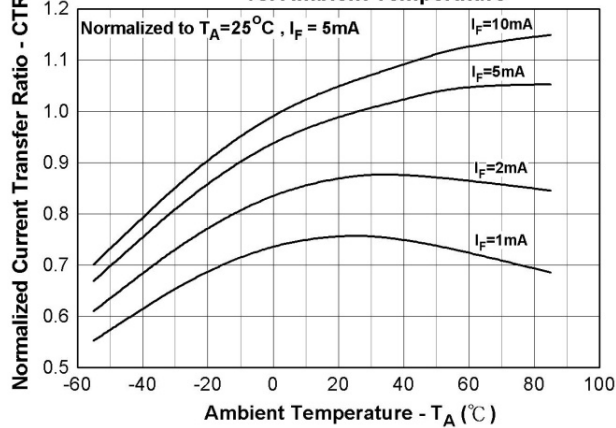


Figure 4. Collector Current vs. Forward Current

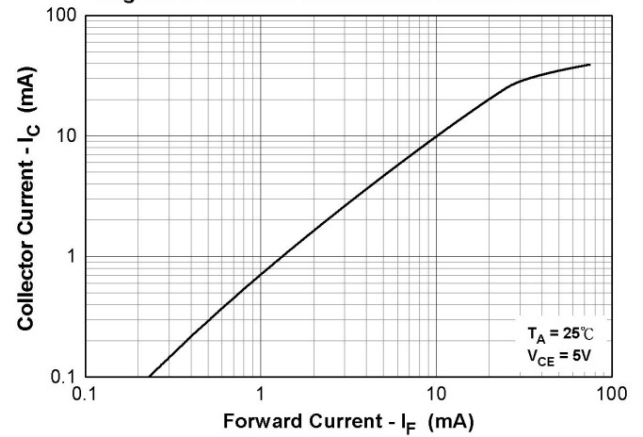


Figure 5. Collector-Emitter Saturation Voltage vs. Collector Current

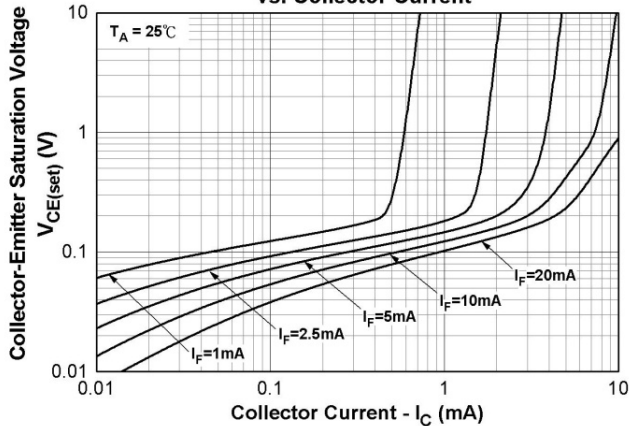


Figure 6. Collector Current vs. Collector Emitter Voltage

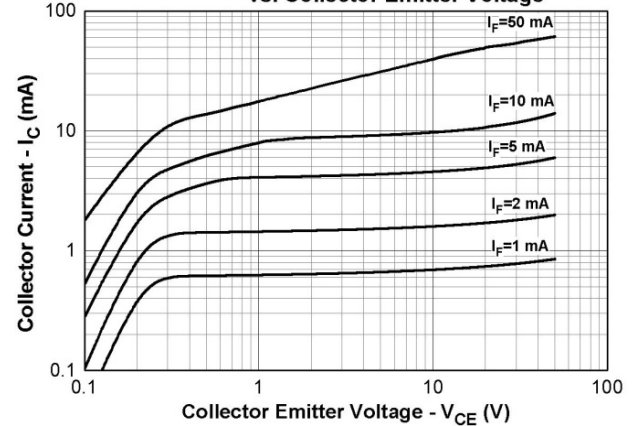


Figure.7 Collector Dark Current
vs. Ambient Temperature

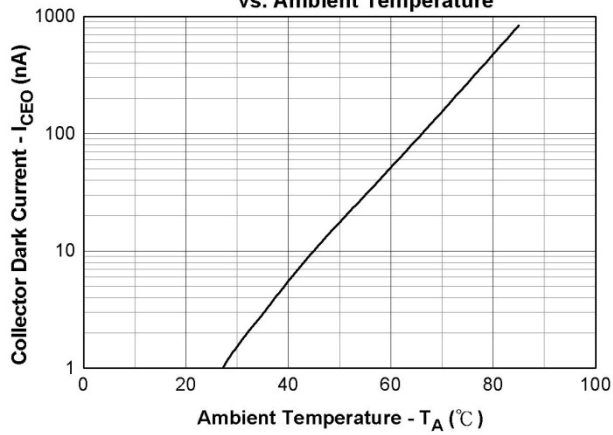


Figure 8. Turn on/off Time vs. Forward Current

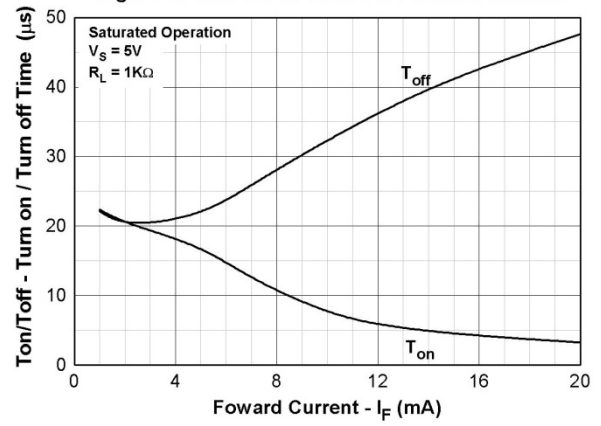


Figure 9. Turn on/off Time vs. Collector Current

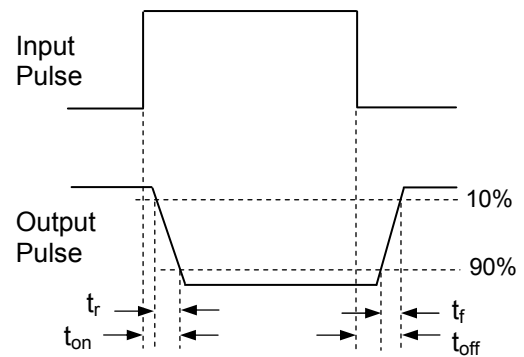
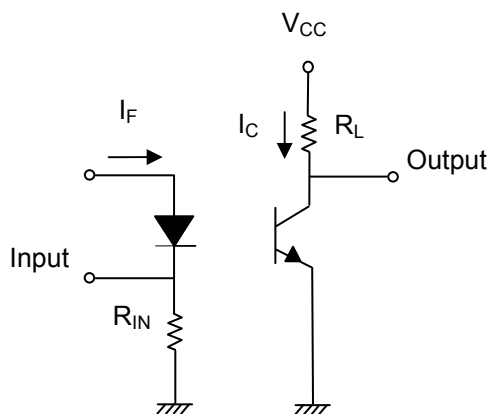
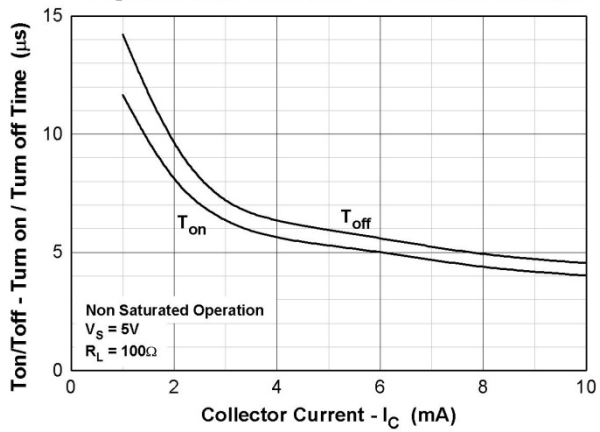


Figure 10. Switching Time Test Circuit & Waveforms

Order Information

Part Number

CNY64Y-V
or
CNY65Y-V

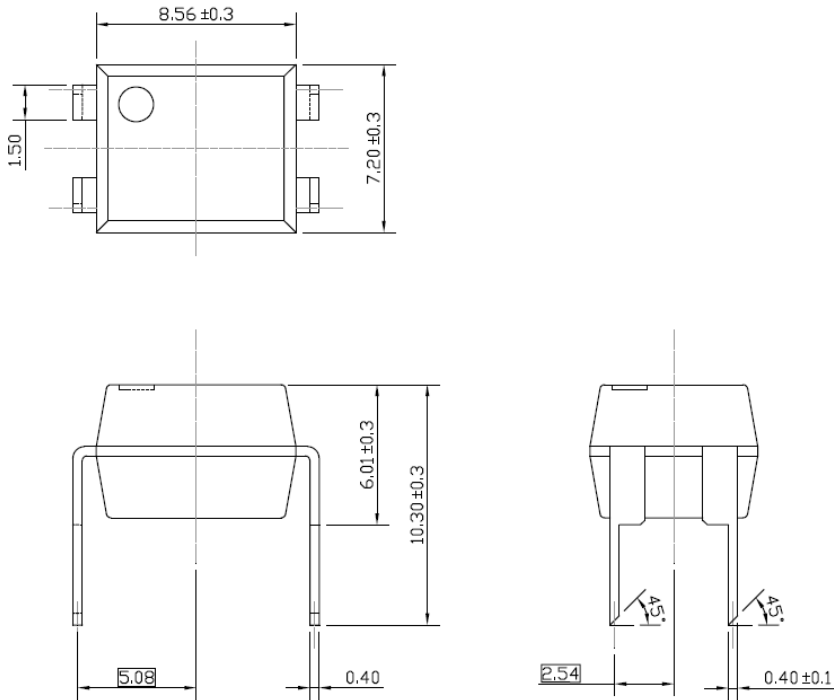
Note

Y = CTR Rank (A, B, or none)
V = VDE safety (optional).

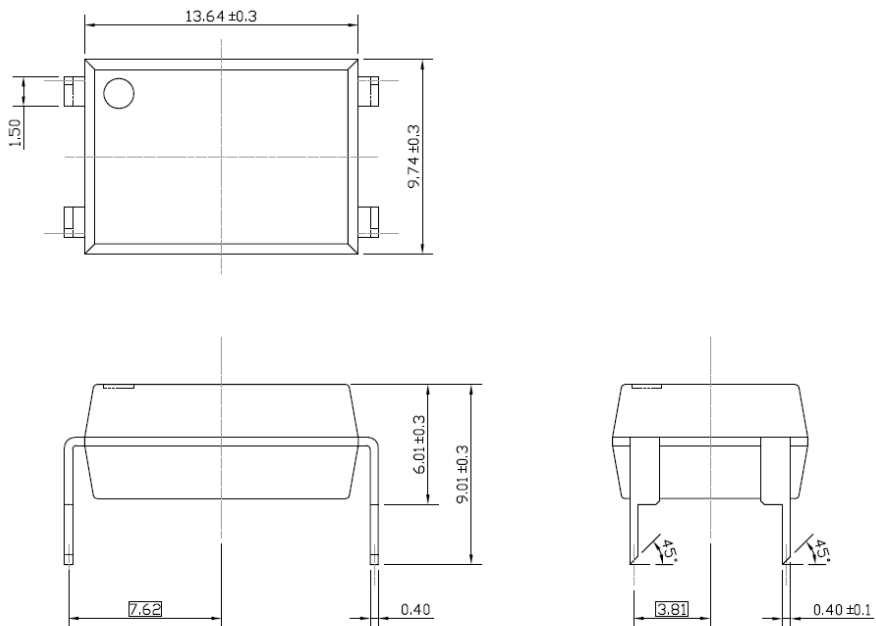
Option	Description	Packing quantity
CNY64	Standard	60 units per tube
CNY64-V	Standard + VDE	60 units per tube
CNY65	Standard	45 units per tube
CNY65-V	Standard + VDE	45 units per tube

Package Dimension (Dimensions in mm)

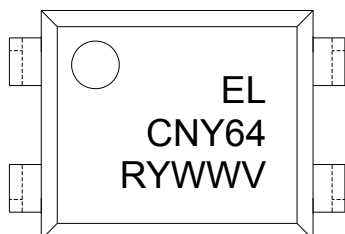
CNY64



CNY65

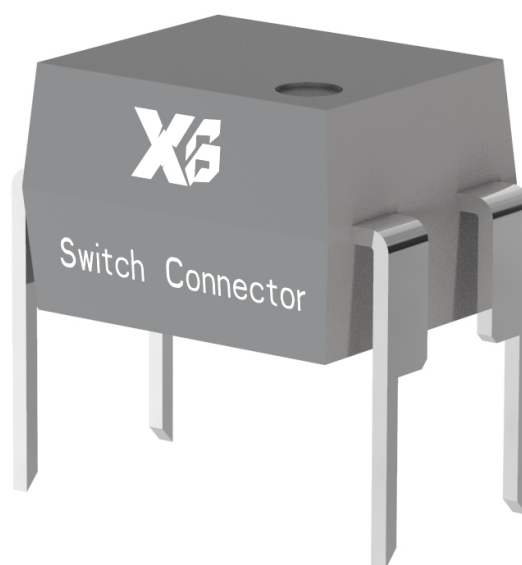


Device Marking



Notes

EL denotes XI BNANG
CNY64 denotes Part no.
R denotes CTR rank (A or B) Y
denotes 1 digit Year code WW
denotes 2 digit Week code V
denotes VDE safety (optional)



DISCLAIMER

1. Above specification may be changed without notice. XI BNANG will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. XI BNANG assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
3. These specification sheets include materials protected under copyright of XI BNANG corporation. Please don't reproduce or cause anyone to reproduce them without XI BNANG's consent.